

SANYO	No.3878	2SA1826/2SC4730
	PNP/NPN Epitaxial Planar Silicon Transistors 100V/3A Switching Applications	

Applications

- Relay drivers, high-speed inverters, converters, and other general high-current switching applications.

Features

- Low collector-to-emitter saturation voltage.
- High Gain-Bandwidth Product.
- Excellent linearity of DC Current Gain.
- Fast switching speed.

() : 2SA1826

Absolute Maximum Ratings at Ta = 25°C

			unit
Collector-to-Base Voltage	V _{CB0}	(-)120	V
Collector-to-Emitter Voltage	V _{CEO}	(-)100	V
Emitter-to-Base Voltage	V _{EBO}	(-)6	V
Collector Current	I _C	(-)3	A
Collector Current (Pulse)	I _{CP}	(-)6	A
Base Current	I _B	(-)0.6	A
Collector Dissipation	P _C	1.5	W
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} = (-)100V, I _E = 0			(-)1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} = (-)4V, I _C = 0			(-)1	μA
DC Current Gain	h _{FE} (1)	V _{CE} = (-)5V, I _C = (-)500mA	100*		400*	
	h _{FE} (2)	V _{CE} = (-)5V, I _C = (-)2A	40			
Gain-Bandwidth Product	f _T	V _{CE} = (-)10V, I _C = (-)500mA		(130)180		MHz
Output Capacitance	C _{ob}	V _{CB} = (-)10V, f = 1MHz		(40)25		pF

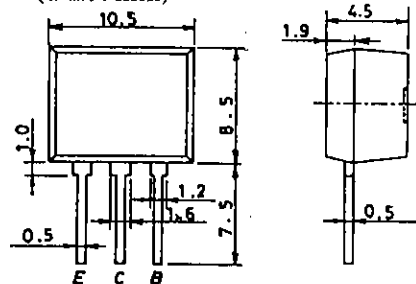
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* : The 2SA1826/2SC4730 are classified by 500mA h_{FE} as follows

100 R 200	140 S 280	200 T 400
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Package Dimensions 2084

(unit: mm)



E : Emitter
C : Collector
B : Base

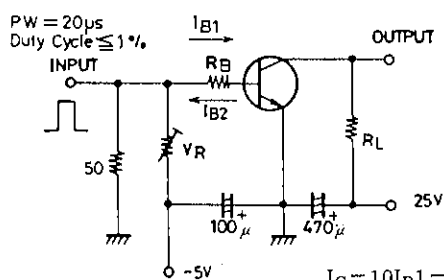
SANYO: FLP

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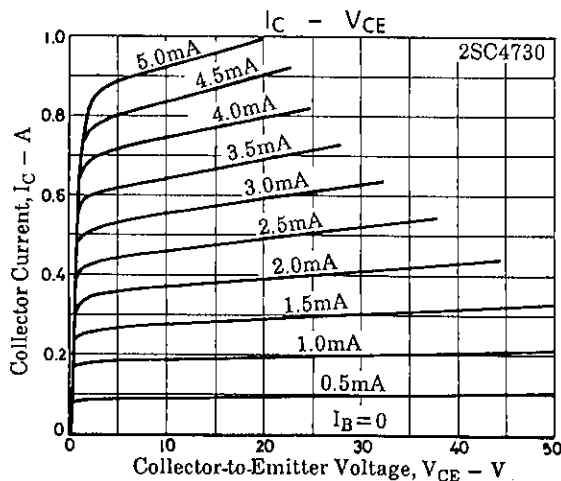
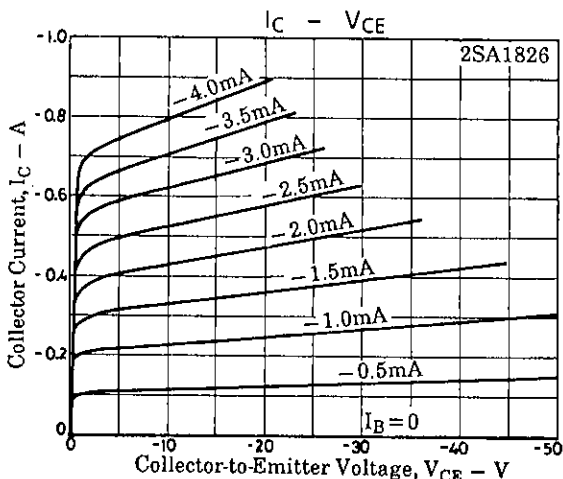
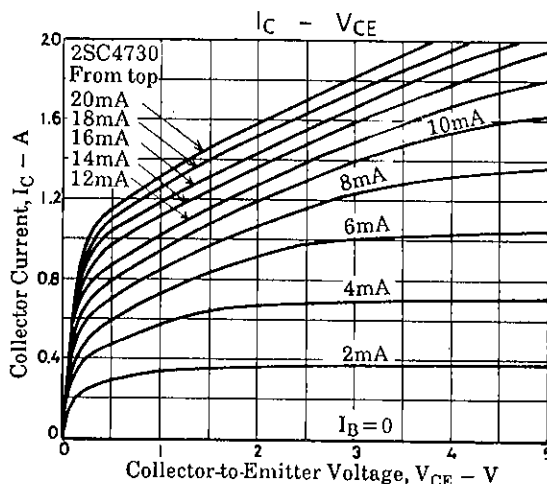
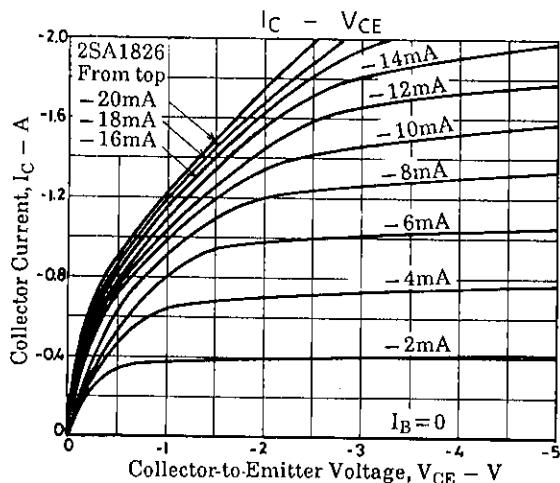
			min	typ	max	unit
C-E Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)1.5A, I_B = (-)0.15A$		(-200)	(-500)	mV
B-E Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)1.5A, I_B = (-)0.15A$		150	400	mV
C-B Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu A, I_E = 0$	(-)	120		V
C-E Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)	100		V
E-B Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu A, I_C = 0$	(-)	6		V
Turn-on Time	t_{on}	See specified Test Circuit.		100		ns
Storage Time	t_{stg}	"		(800)900		ns
Fall Time	t_f	"		50		ns

Switching Time Test Circuit

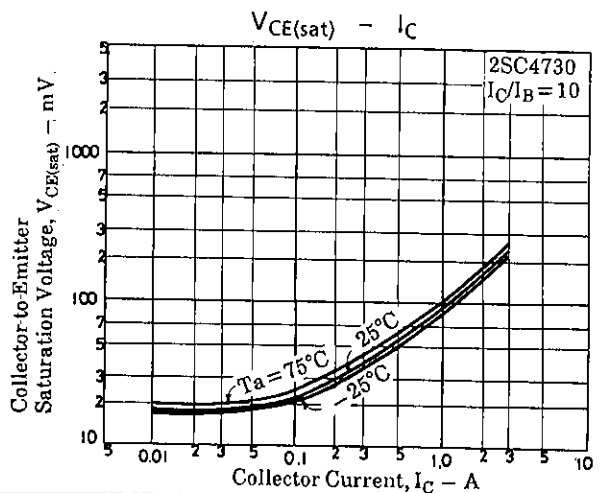
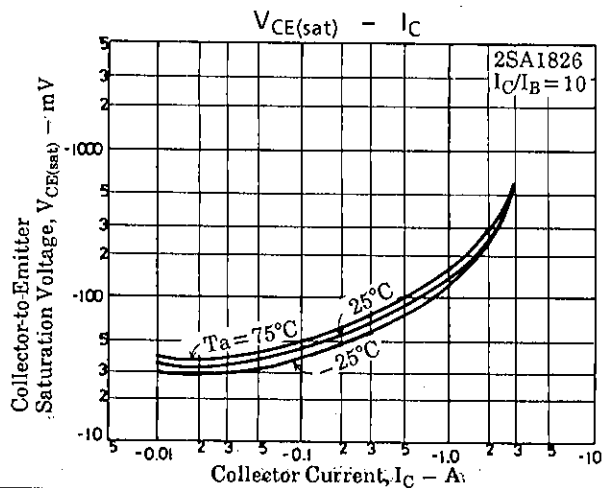
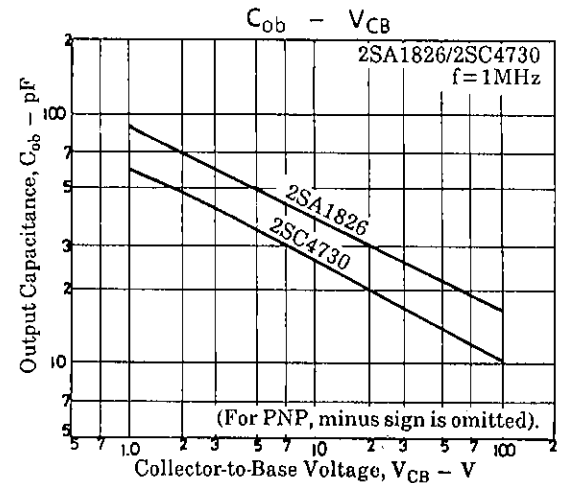
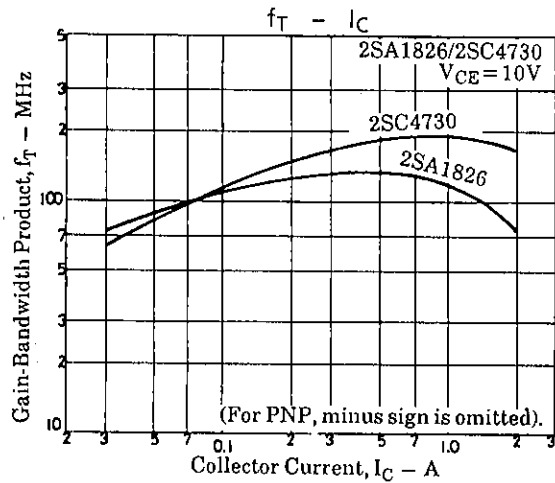
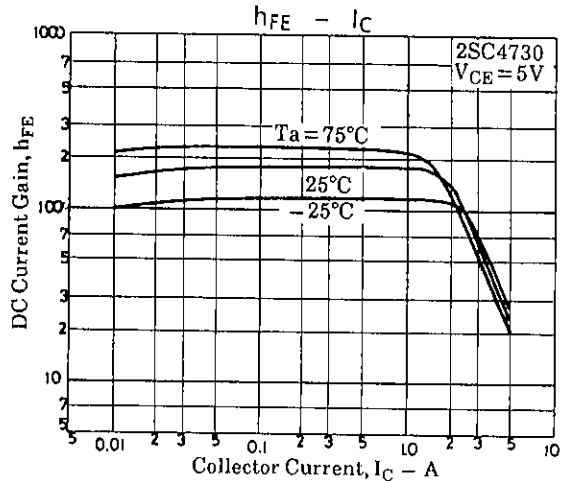
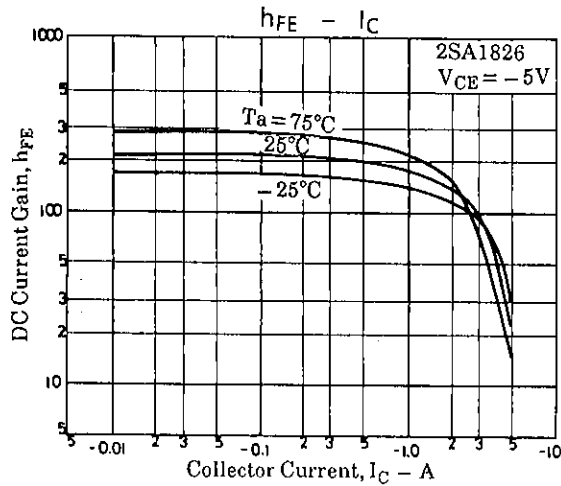
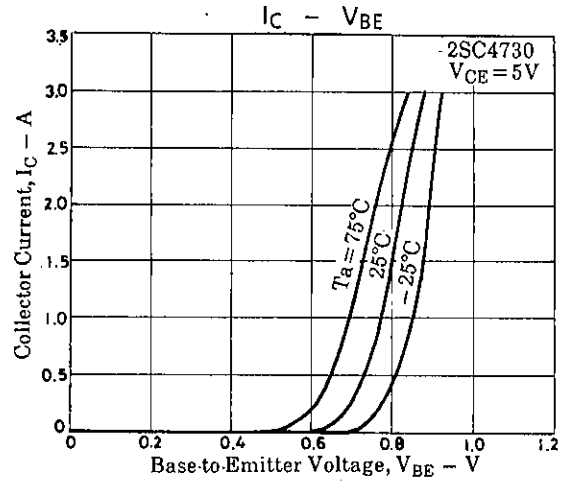
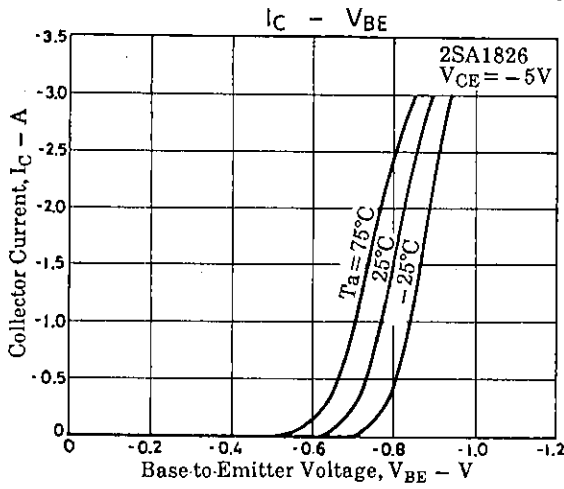


$I_C = 10I_{B1} = -10I_{B2} = 1.5A$
(For PNP, the polarity is reversed).

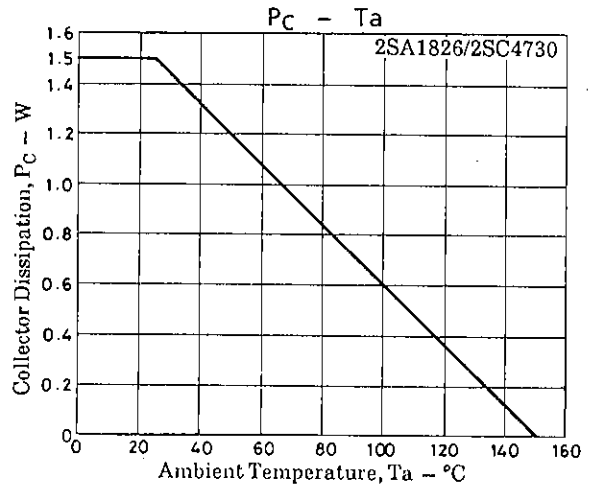
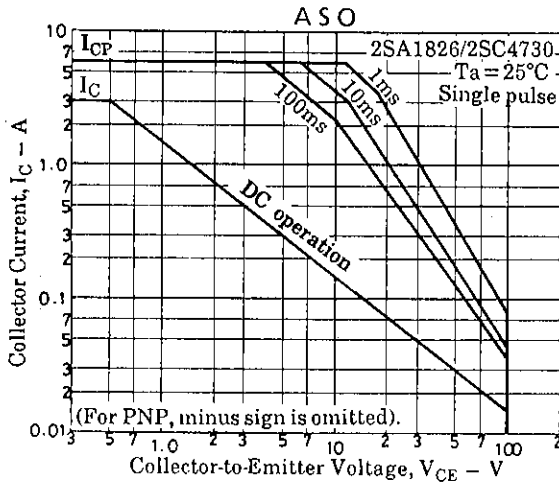
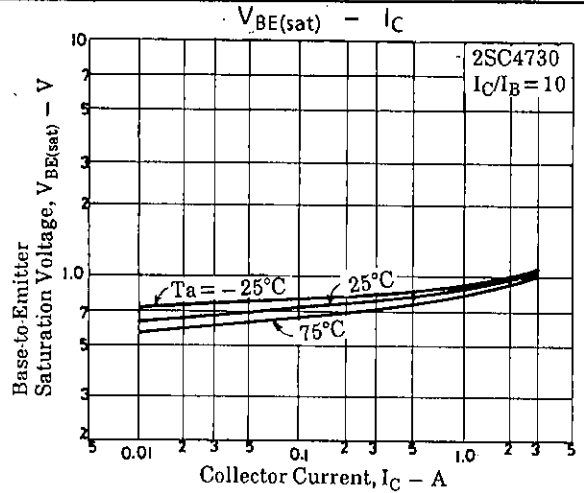
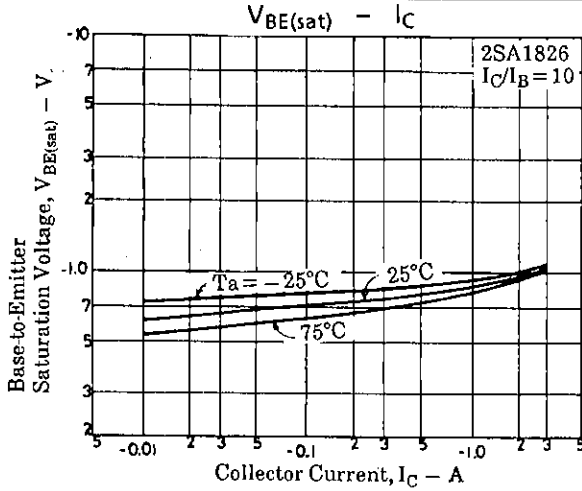
Unit (resistance: Ω , capacitance: F)



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